S1C17F57



Low Power 16-bit Single Chip Microcontroller • Low power MCU (100nA/SLEEP, 210nA/RTC, 550nA/HALT) • Flash memory (32K bytes), RAM (2K bytes) • Built-in EPD driver (voltage booster circuit)

- EPD driving waveform generator circuit
- Real-time clock
- Built-in temperature sensor
- Compact codes optimized for C, and high throughput of an instruction/clock. Support serial ICE, and comes equipped with RISC CPU core S1C17.

DESCRIPTIONS

S1C17F57 is a 16-bit MCU that has achieved high processing speeds with low voltage operation, compact size, wide address space and on-chip ICE. It consists of a 16-bit core CPU S1C17 as the core CPU, 32K bytes flash memory, 2K bytes RAM, Serial I/F such as UART/SPI/I2C, timers, real-time clock, multiplier circuit. In addition, it has 64 segment EPD driver, EPD driving waveform generator circuit, temperature sensor. It can drive E-paper display by 1chip. S1C17F57 is suitable for battery driven and E-paper application like smartcard, watch, and tags.

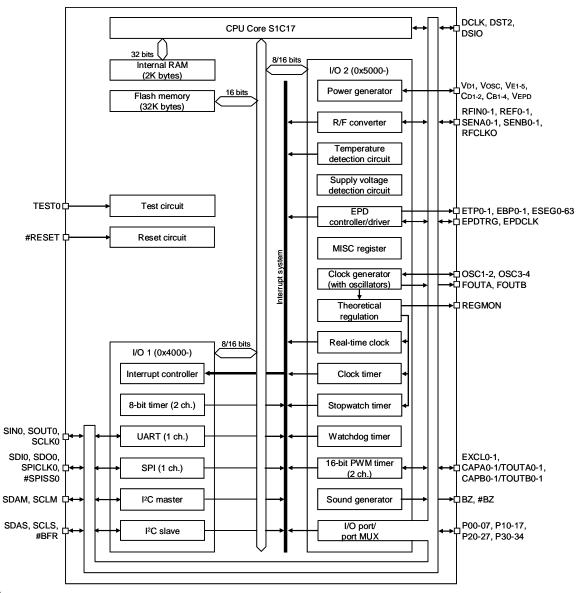
■ FEATURES

CPU		
CPU core	Seiko Epson original 16-bit RISC CPU core S1C17	
Multiplier/Divider (COPRO)	- 16-bit x 16-bit multiplier	
	- 16-bit × 16-bit + 32-bit multiply and accumulation unit	
	- 16-bit ÷ 16-bit divider	
Embedded Flash memory		
Capacity	32K bytes (for both instructions and data)	
Erase/program count	Three times	
Other	- Read/program protection function	
	- A programming power supply (VPP) is required.	
	- Allows on-board programming using a debugging tool such as ICDmini.	
Embedded RAM		
Capacity	2K bytes	
Clock generator		
System clock source	3 sources (OSC3B/OSC3A/OSC1)	
OSC3B oscillator circuit	2M/1M/500k Hz (typ.) internal oscillator circuit	
OSC3A oscillator circuit	4.2 MHz (max.) crystal or ceramic oscillator circuit	
OSC1B oscillator circuit	32 kHz (typ.) internal oscillator circuit	
OSC1A oscillator circuit	32.768 kHz (typ.) crystal oscillator circuit	
	Oscillation adjustment by theoretical regulation	
Other	- Core clock frequency control	
	- Peripheral module clock supply control	
EPD controller/driver		
Number of driver outputs	Segment output: 64 pins	
	Top plane output: 2 pins	
	Back plane output: 2 pins	
Drive voltage	0 V/15 V (VSS/VEPD)	
Other	- Includes a drive power supply.	
	- Includes a display data memory.	
	- Output drive waveforms can be programmed.	
	- Supports pin output direct control.	
I/O ports		
Number of general-purpose I/O ports	Max. 29 bits (Pins are shared with the peripheral I/O.)	
Other	- Schmitt input	
	- Pull-up control function	
	- Port input interrupt: 8 bits x 2 channels	
Serial interfaces		
SPI	1 channel	
I ² C master (I2CM)	1 channel	
I ² C slave (I2CS)	1 channel	
UART	1 channel (IrDA1.0 supported)	
Timers/Counters		
8-bit timer (T8)	2 channels (Generates the SPI Ch.0 and I2CM clocks.)	

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16-bit PWM timer (T16A2)	2 channels (PWM output, event counter, and count capture functions)	
Watchdog timer (WDT)	1 channel (Generates NMI/reset.)	
Clock functions		
Real-time clock (RTC)	1 channel	
	(Hour, minute, and second counters) with theoretical regulation support	
Clock timer (CT)	1 channel (128 Hz to 1 Hz counters) with theoretical regulation support	
Stopwatch timer (SWT)	1 channel	
	(1/100 second and 1/10 second counters) with theoretical regulation support	
Theoretical regulation function (TR)	Time adjustment function in +16/32768 to -15/32768 second units	
Sound generator		
Buzzer frequency	8 frequencies selectable	
Volume control	8 steps adjustable	
Other	- One-shot buzzer	
	- Auto envelope function	
Analog circuits		
R/F converter (RFC)	2 channels (24-bit CR oscillation type. Supports DC-bias resistive sensors and	
	AC-bias resistive sensors.)	
Temperature detection circuit (TEM)	1 channel (Measurement range: 0°C to 50°C)	
Supply voltage detection circuit (SVD)	1 channel (Detection voltage: 13 levels)	
Interrupts		
Reset interrupt	#RESET pin/watchdog timer	
NMI	Watchdog timer	
Programmable interrupts	16 systems (8 levels)	
Power supply voltage		
Operating voltage (VDD)	2.0 V to 3.6 V	
Flash programming/erasing voltage (VPP)	7 V/7.5 V	
Operating temperature		
Operating temperature range	-40°C to 85°C	
Current consumption (Typ value, VDD = 2.0 V to 3.6 V)		
SLEEP state	100 nA (OSC1 = Off, RTC = Off, OSC3B = Off, OSC3A = Off)	
HALT state	0.55 μA (OSC1 = 32 kHz (OSC1A), RTC = Off, OSC3B = Off, OSC3A = Off)	
	0.5 μA (OSC1 = 32 kHz (OSC1A), RTC = On, OSC3B = Off, OSC3A = Off)	
Run state	12 μA (OSC1 = 32 kHz (OSC1A), RTC = Off, OSC3B = Off, OSC3A = Off)	
	1440 μA (OSC1 = Off, RTC = Off, OSC3B = Off, OSC3A = 4 MHz ceramic)	
	770 µA (OSC1 = Off, RTC = Off, OSC3B = 2 MHz, OSC3A = Off)	
Shipping form		
1	QFP15-128pin (14 mm × 14 mm × 1.4 mm, lead pitch: 0.4 mm)	
2	Aluminum pad chip	
3	Gold bump chip	

■ BLOCK DIAGRAM



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